



Vincotech

| MiniSKiiP® 1 PIM   |  | 1200 V / 8 A                |
|--|--|-----------------------------|
| <b>Features</b>  |  |                             |
| <ul style="list-style-type: none"><li>• Solderless interconnection</li><li>• Trench Fieldstop IGBT3 technology</li></ul> |  |                             |
| <b>Target Applications</b>   |  | <b>MiniSKiiP® 1 housing</b> |
| <ul style="list-style-type: none"><li>• Industrial drives</li></ul>  |  |                             |
| <b>Types</b>   |  | <b>Schematic</b>            |
| <ul style="list-style-type: none"><li>• V23990-K209-A-PM</li></ul>   |  |                             |

## Maximum Ratings

 $T_j = 25^\circ\text{C}$ , unless otherwise specified

| Parameter                              | Symbol           | Condition                               | Value                    | Unit                 |   |
|--|------------------|---|--------------------------|----------------------|---|
| <b>Rectifier Diode</b>                 |                  |   |                          |                      |   |
| Repetitive peak reverse voltage        | $V_{RRM}$        |   | 1600                     | V                    |   |
| DC forward current                     | $I_{FAV}$        |   | 25                       | A                    |   |
| Surge (non-repetitive) forward current | $I_{FSM}$        | $t_p = 10 \text{ ms}$<br>half sine wave | 220                      | A                    |   |
| $I^2t$ -value                          | $I^2t$           |   | 240                      | $\text{A}^2\text{s}$ |   |
| Power dissipation                      | $P_{\text{tot}}$ | $T_j = T_{j\max}$                       | $T_s = 80^\circ\text{C}$ | 46                   | W |
| Maximum Junction Temperature           | $T_{j\max}$      |   |                          | $150^\circ\text{C}$  |   |

## Inverter Switch / Brake Switch

|                                     |                  |   |                          |                     |   |
|-------------------------------------|------------------|---|--------------------------|---------------------|---|
| Collector-emitter breakdown voltage | $V_{CE}$         |   | 1200                     | V                   |   |
| DC collector current                | $I_C$            |   | 8                        | A                   |   |
| Repetitive peak collector current   | $I_{CRM}$        | $t_p$ limited by $T_{j\max}$  | 24                       | A                   |   |
| Power dissipation                   | $P_{\text{tot}}$ | $T_j = T_{j\max}$   | $T_s = 80^\circ\text{C}$ | 62                  | W |
| Gate-emitter peak voltage           | $V_{GE}$         |   | $\pm 20$                 | V                   |   |
| Short circuit ratings               | $t_{SC}$         | $T_j \leq 150^\circ\text{C}$ $V_{GE} = 15 \text{ V}$ $V_{cc} = 900 \text{ V}$ | 10                       | $\mu\text{s}$       |   |
| Maximum Junction Temperature        | $T_{j\max}$      |   |                          | $175^\circ\text{C}$ |   |



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V23990-K209-A-PM

datasheet

## Maximum Ratings

$T_j = 25^\circ\text{C}$ , unless otherwise specified

| Parameter                           | Symbol     | Condition                                    | Value | Unit             |
|-------------------------------------|------------|--|-------|------------------|
| <b>Inverter Diode / Brake Diode</b> |            |  |       |                  |
| Repetitive peak reverse voltage     | $V_{RRM}$  |  | 1200  | V                |
| DC forward current                  | $I_F$      |  | 12    | A                |
| Repetitive peak forward current     | $I_{FRM}$  | $t_p$ limited by $T_{jmax}$                  | 29    | A                |
| Power dissipation                   | $P_{tot}$  | $T_j = T_{jmax}$<br>$T_s = 80^\circ\text{C}$ | 28    | W                |
| Maximum Junction Temperature        | $T_{jmax}$ |  | 150   | $^\circ\text{C}$ |

## Thermal Properties

|   |           |  |                            |                  |
|---|-----------|--|----------------------------|------------------|
| Storage temperature                             | $T_{stg}$ |  | -40...+125                 | $^\circ\text{C}$ |
| Operation temperature under switching condition | $T_{op}$  |  | -40...+( $T_{jmax} - 25$ ) | $^\circ\text{C}$ |

## Isolation Properties

|                            |          |   |                  |      |    |
|----------------------------|----------|---|------------------|------|----|
| Isolation voltage          | $V_{is}$ | $t = 2\text{ s}$  | DC Test Voltage* | 5500 | V  |
|                            |          | $t = 1\text{ min}$  | AC Voltage       | 2500 | V  |
| Creepage distance          |          | With std lid<br>For more informations see handling instructions |                  | 6,3  | mm |
| Clearance                  |          | With std lid<br>For more informations see handling instructions |                  | 6,3  | mm |
| Comparative Tracking Index | CTI      |   |                  | >200 |    |

\* 100 % tested in production



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## Characteristic Values

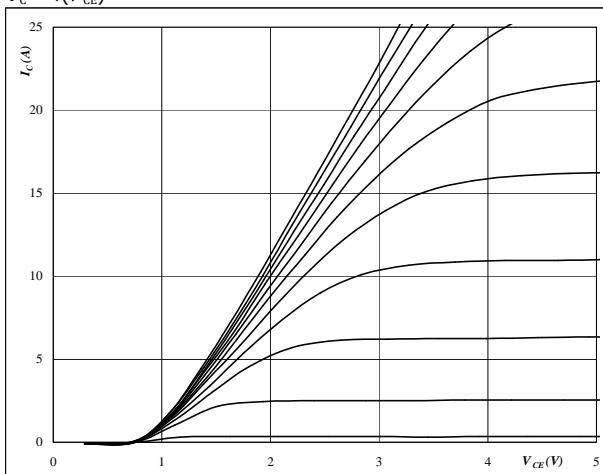
| Parameter                                     | Symbol               | Conditions                                      |              |           |                       |              |                       | Value        |  |                        | Unit |
|---|----------------------|---|--------------|-----------|-----------------------|--------------|-----------------------|--------------|--|------------------------|------|
|   |                      | $V_{GE}$ [V]                                    | $V_r$ [V]    | $I_c$ [A] | $T_j$ [ $^{\circ}$ C] | Min          | Typ                   | Max          |  |                        |      |
|   |                      | $V_{GS}$ [V]                                    | $V_{CE}$ [V] | $I_F$ [A] | $I_D$ [A]             |              |                       |              |  |                        |      |
| <b>Rectifier Diode</b>                        |                      |   |              |           |                       |              |                       |              |  |                        |      |
| Forward voltage                               | $V_F$                |   |              | 15        | 25<br>125             | 1,08<br>1,05 | 1,22<br>1,18          | 1,35<br>1,3  |  | V                      |      |
| Threshold voltage (for power loss calc. only) | $V_{to}$             |   |              | 15        | 25<br>125             | 0,85<br>0,71 | 0,89<br>0,77          | 0,96<br>0,83 |  | V                      |      |
| Slope resistance (for power loss calc. only)  | $r_t$                |   |              | 15        | 25<br>125             | 18<br>19     | 21<br>27              | 26<br>34     |  | m $\Omega$             |      |
| Reverse current                               | $I_r$                |   | 1600         |           | 25                    |              |                       | 0,05         |  | mA                     |      |
| Thermal resistance junction to sink           | $R_{th(j-s)}$        | $\lambda_{paste} = 2,5 \text{ W/mK}$<br>(HPTP)  |              |           |                       |              |                       | 1,37         |  | K/W                    |      |
| <b>Inverter Switch / Brake Switch</b>         |                      |   |              |           |                       |              |                       |              |  |                        |      |
| Gate emitter threshold voltage                | $V_{GE(th)}$         | $V_{CE} = V_{GE}$                               |              | 0,00015   | 25                    | 5            | 5,8                   | 6,5          |  | V                      |      |
| Collector-emitter saturation voltage          | $V_{CEsat}$          |   | 15           | 8         | 25<br>150             | 1,35         | 1,75<br>1,85          | 2,05         |  | V                      |      |
| Collector-emitter cut-off current incl. Diode | $I_{CES}$            |   | 0            | 1200      |                       | 25           |                       | 0,05         |  | mA                     |      |
| Gate-emitter leakage current                  | $I_{GES}$            |   | 20           | 0         | 25                    |              |                       | 120          |  | nA                     |      |
| Integrated Gate resistor                      | $R_{gint}$           |   |              |           |                       |              | none                  |              |  | $\Omega$               |      |
| Turn-on delay time                            | $t_{d(on)}$          | $R_{goff} = 54 \Omega$<br>$R_{gon} = 54 \Omega$ | $\pm 15$     | 600       | 8                     | 25<br>150    | 46<br>44              |              |  | ns                     |      |
| Rise time                                     | $t_r$                |   |              |           |                       | 25<br>150    | 21<br>27              |              |  |                        |      |
| Turn-off delay time                           | $t_{d(off)}$         |   |              |           |                       | 25<br>150    | 317<br>385            |              |  |                        |      |
| Fall time                                     | $t_f$                |   |              |           |                       | 25<br>150    | 96<br>174             |              |  |                        |      |
| Turn-on energy loss                           | $E_{on}$             |   |              |           |                       | 25<br>150    | 0,65<br>0,82          |              |  | mWs                    |      |
| Turn-off energy loss                          | $E_{off}$            |   |              |           |                       | 25<br>150    | 0,54<br>0,82          |              |  |                        |      |
| Input capacitance                             | $C_{ies}$            |   |              |           |                       |              | 551                   |              |  |                        |      |
| Output capacitance                            | $C_{oss}$            |   |              |           |                       | 25           | 40                    |              |  | pF                     |      |
| Reverse transfer capacitance                  | $C_{rss}$            | $f = 1 \text{ MHz}$                             | $\pm 15$     | 600       | 8                     |              | 17                    |              |  |                        |      |
| Gate charge                                   | $Q_G$                |   |              |           |                       | 25           | 58                    |              |  | nC                     |      |
| Thermal resistance junction to sink           | $R_{th(j-s)}$        |   |              |           |                       |              | 1,36                  |              |  | K/W                    |      |
| <b>Inverter Diode / Brake Diode</b>           |                      |   |              |           |                       |              |                       |              |  |                        |      |
| Diode forward voltage                         | $V_F$                |   |              | 5         | 25<br>125             |              | 1,55<br>1,57          | 1,77         |  | V                      |      |
| Peak reverse recovery current                 | $I_{RRM}$            | $di_V/dt = tbd \text{ A/us}$                    | $\pm 15$     | 600       | 8                     | 25<br>125    | 7,8<br>8,8            |              |  | A                      |      |
| Reverse recovery time                         | $t_{rr}$             |   |              |           |                       | 25<br>125    | 434<br>610            |              |  | ns                     |      |
| Reverse recovered charge                      | $Q_{rr}$             |   |              |           |                       | 25<br>125    | 1,16<br>1,77          |              |  | $\mu\text{C}$          |      |
| Peak rate of fall of recovery current         | $(di_{rf}/dt)_{max}$ |   |              |           |                       | 25<br>125    | 75<br>38              |              |  | $\text{A}/\mu\text{s}$ |      |
| Reverse recovered energy                      | $E_{rec}$            |   |              |           |                       | 25<br>125    | 0,48<br>0,75          |              |  | mWs                    |      |
| Thermal resistance junction to sink           | $R_{th(j-s)}$        |   |              |           |                       |              | 2,13                  |              |  | K/W                    |      |
| <b>Thermistor</b>                             |                      |   |              |           |                       |              |                       |              |  |                        |      |
| Rated resistance                              | $R$                  |   |              |           | 25                    |              | 1000                  |              |  | $\Omega$               |      |
| Deviation of $R_{100}$                        | $\Delta R/R$         | $R_{100} = 1670 \Omega$                         |              |           | 100                   | -3           | 3                     |              |  | %                      |      |
| $R_{100}$                                     | $R$                  |   |              |           | 100                   |              | 1670,3125             |              |  | $\Omega$               |      |
| A-value                                       | $B_{(25/50)}$        |   |              |           | 25                    |              | $7,635 \cdot 10^{-3}$ |              |  | 1/K                    |      |
| B-value                                       | $B_{(25/100)}$       |   |              |           | 25                    |              | $1,731 \cdot 10^{-5}$ |              |  | 1/K <sup>2</sup>       |      |
| Vincotech NTC Reference                       |                      |   |              |           |                       |              |                       | E            |  |                        |      |

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## Inverter Switch / Brake Switch / Inverter Diode / Brake Diode

**figure 1.**
**Typical output characteristics**

$$I_C = f(V_{CE})$$


**At**

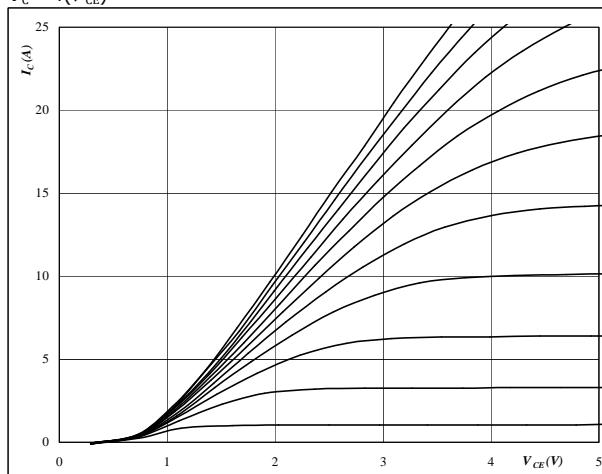
$$t_p = 250 \mu\text{s}$$

$$T_j = 25^\circ\text{C}$$

 $V_{GE}$  from 7 V to 17 V in steps of 1 V

**IGBT**
**figure 2.**
**Typical output characteristics**

$$I_C = f(V_{CE})$$


**At**

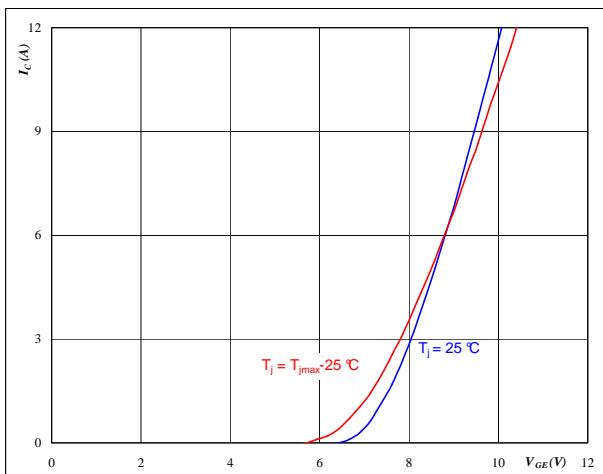
$$t_p = 250 \mu\text{s}$$

$$T_j = 125^\circ\text{C}$$

 $V_{GE}$  from 7 V to 17 V in steps of 1 V

**IGBT**
**figure 3.**
**IGBT**
**Typical transfer characteristics**

$$I_C = f(V_{GE})$$

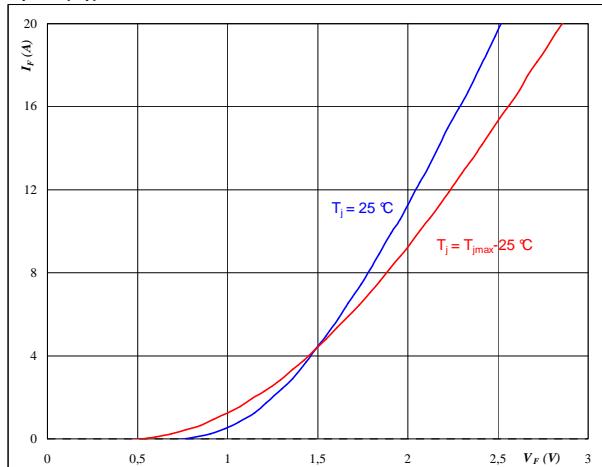

**At**

$$t_p = 250 \mu\text{s}$$

$$V_{CE} = 10 \text{ V}$$

**figure 4.**
**FWD**
**Typical diode forward current as a function of forward voltage**

$$I_F = f(V_F)$$


**At**

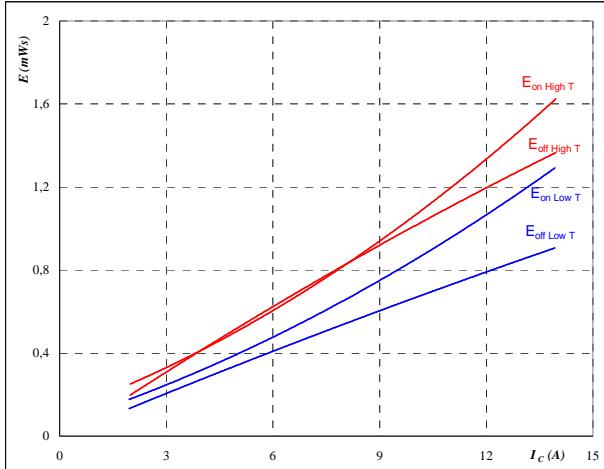
$$t_p = 250 \mu\text{s}$$

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## Inverter Switch / Brake Switch / Inverter Diode / Brake Diode

**figure 5.**
**IGBT**
**Typical switching energy losses  
as a function of collector current**

$$E = f(I_C)$$



With an inductive load at

$$T_j = 25/125 \text{ } ^\circ\text{C}$$

$$V_{CE} = 600 \text{ V}$$

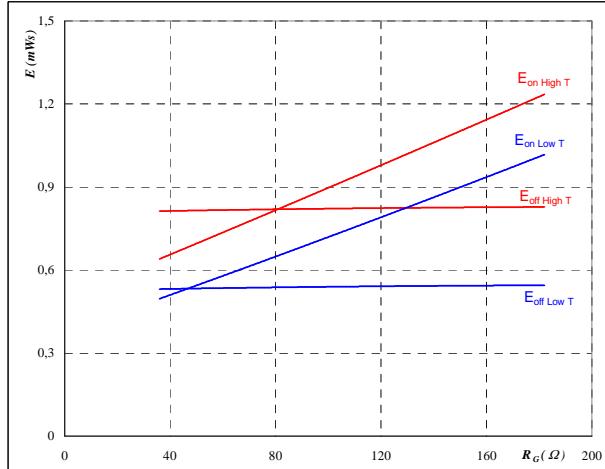
$$V_{GE} = \pm 15 \text{ V}$$

$$R_{gon} = 81 \text{ } \Omega$$

$$R_{goff} = 81 \text{ } \Omega$$

**figure 6.**
**IGBT**
**Typical switching energy losses  
as a function of gate resistor**

$$E = f(R_G)$$



With an inductive load at

$$T_j = 25/125 \text{ } ^\circ\text{C}$$

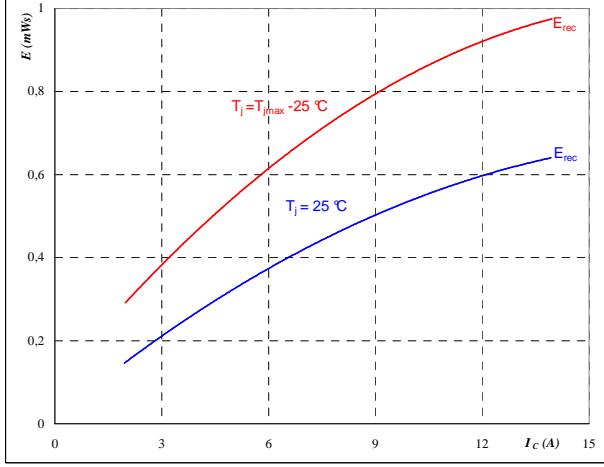
$$V_{CE} = 600 \text{ V}$$

$$V_{GE} = \pm 15 \text{ V}$$

$$I_C = 8 \text{ A}$$

**figure 7.**
**FWD**
**Typical reverse recovery energy loss  
as a function of collector current**

$$E_{rec} = f(I_C)$$



With an inductive load at

$$T_j = 25/125 \text{ } ^\circ\text{C}$$

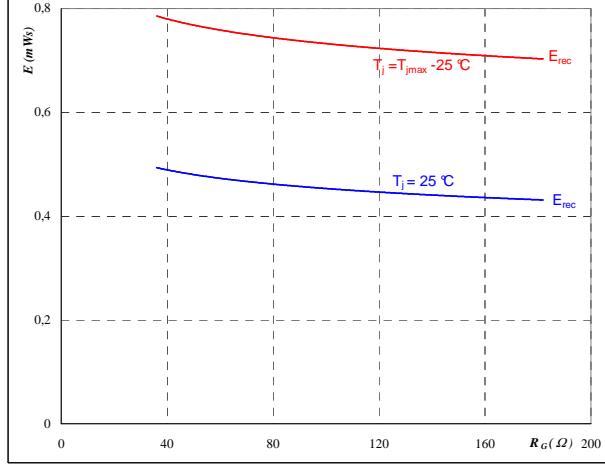
$$V_{CE} = 600 \text{ V}$$

$$V_{GE} = \pm 15 \text{ V}$$

$$R_{gon} = 81 \text{ } \Omega$$

**figure 8.**
**FWD**
**Typical reverse recovery energy loss  
as a function of gate resistor**

$$E_{rec} = f(R_G)$$



With an inductive load at

$$T_j = 25/125 \text{ } ^\circ\text{C}$$

$$V_{CE} = 600 \text{ V}$$

$$V_{GE} = \pm 15 \text{ V}$$

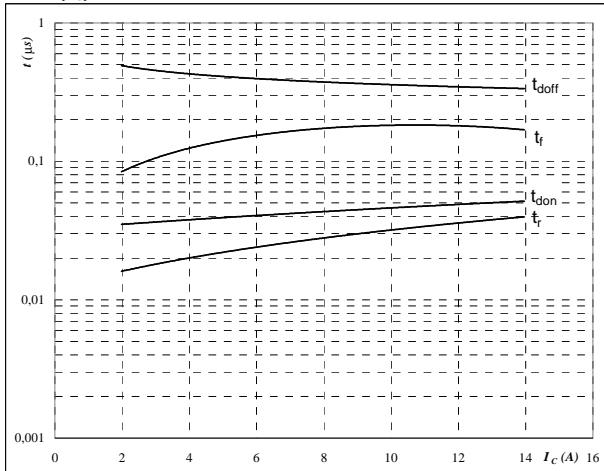
$$I_C = 8 \text{ A}$$

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## Inverter Switch / Brake Switch / Inverter Diode / Brake Diode

**figure 9.**
**IGBT**
**Typical switching times as a function of collector current**

$$t = f(I_C)$$



With an inductive load at

$$T_j = 125 \text{ } ^\circ\text{C}$$

$$V_{CE} = 600 \text{ V}$$

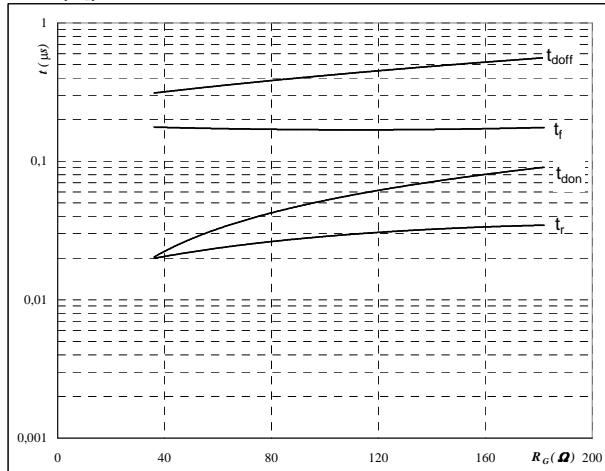
$$V_{GE} = \pm 15 \text{ V}$$

$$R_{gon} = 81 \Omega$$

$$R_{goff} = 81 \Omega$$

**figure 10.**
**IGBT**
**Typical switching times as a function of gate resistor**

$$t = f(R_G)$$



With an inductive load at

$$T_j = 125 \text{ } ^\circ\text{C}$$

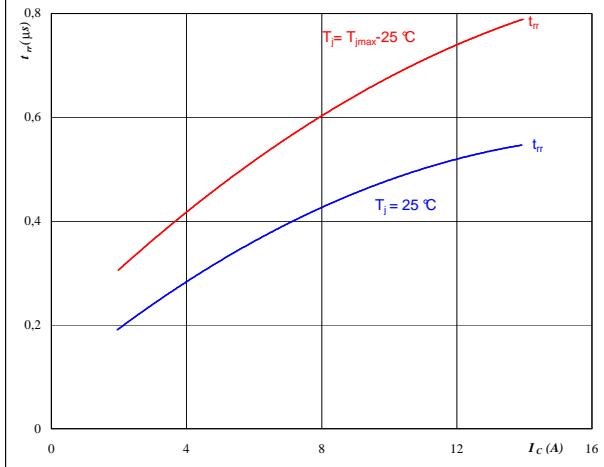
$$V_{CE} = 600 \text{ V}$$

$$V_{GE} = \pm 15 \text{ V}$$

$$I_C = 8 \text{ A}$$

**figure 11.**
**FWD**
**Typical reverse recovery time as a function of collector current**

$$t_{rr} = f(I_C)$$


**At**

$$T_j = 25/125 \text{ } ^\circ\text{C}$$

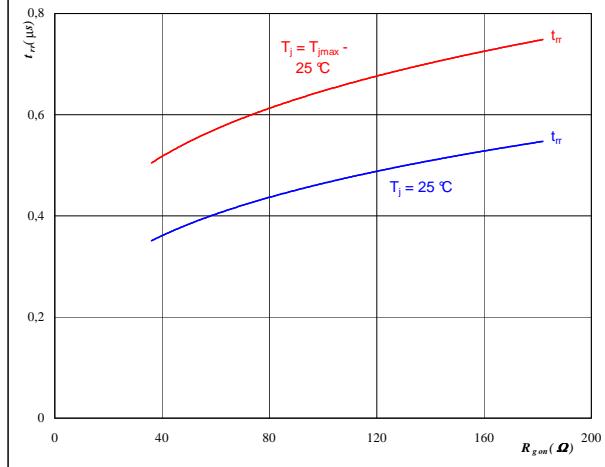
$$V_{CE} = 600 \text{ V}$$

$$V_{GE} = \pm 15 \text{ V}$$

$$R_{gon} = 81 \Omega$$

**figure 12.**
**FWD**
**Typical reverse recovery time as a function of IGBT turn on gate resistor**

$$t_{rr} = f(R_{gon})$$


**At**

$$T_j = 25/125 \text{ } ^\circ\text{C}$$

$$V_R = 600 \text{ V}$$

$$I_F = 8 \text{ A}$$

$$V_{GE} = \pm 15 \text{ V}$$

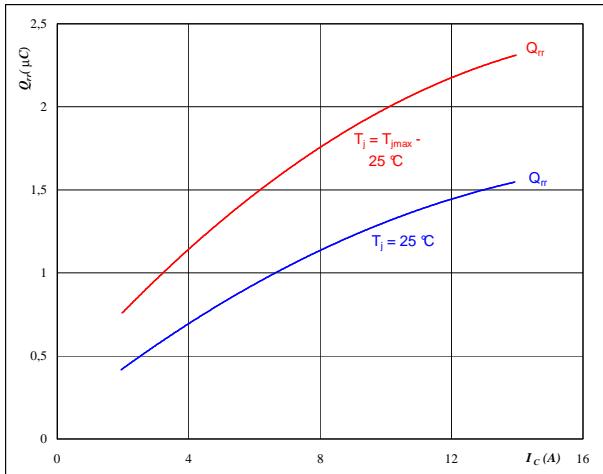
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## Inverter Switch / Brake Switch / Inverter Diode / Brake Diode

**figure 13.**
**FWD**

Typical reverse recovery charge as a function of collector current

$$Q_{rr} = f(I_c)$$


**At**

$$T_j = 25/125 \text{ } ^{\circ}\text{C}$$

$$V_{CE} = 600 \text{ V}$$

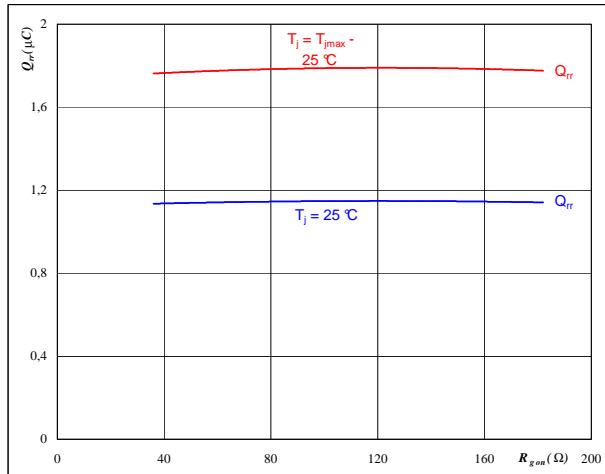
$$V_{GE} = \pm 15 \text{ V}$$

$$R_{gon} = 81 \Omega$$

**figure 14.**
**FWD**

Typical reverse recovery charge as a function of IGBT turn on gate resistor

$$Q_{rr} = f(R_{gon})$$


**At**

$$T_j = 25/125 \text{ } ^{\circ}\text{C}$$

$$V_R = 600 \text{ V}$$

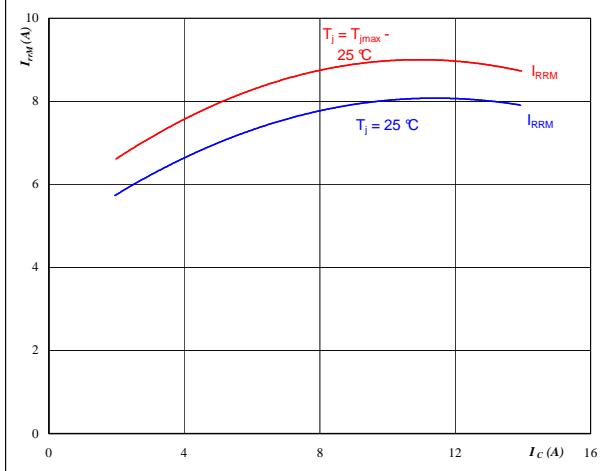
$$I_F = 8 \text{ A}$$

$$V_{GE} = \pm 15 \text{ V}$$

**figure 15.**
**FWD**

Typical reverse recovery current as a function of collector current

$$I_{RRM} = f(I_c)$$


**At**

$$T_j = 25/125 \text{ } ^{\circ}\text{C}$$

$$V_{CE} = 600 \text{ V}$$

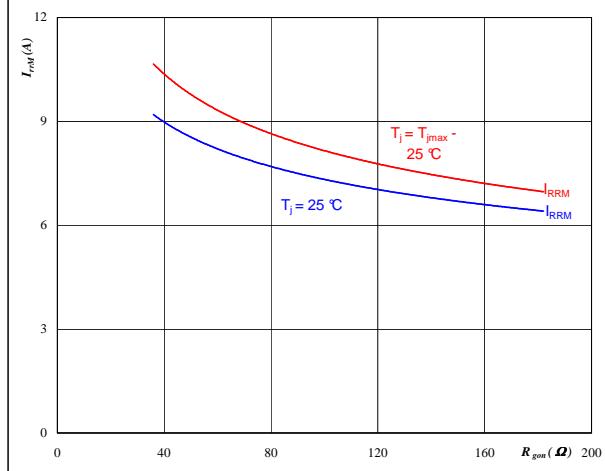
$$V_{GE} = \pm 15 \text{ V}$$

$$R_{gon} = 81 \Omega$$

**figure 16.**
**FWD**

Typical reverse recovery current as a function of IGBT turn on gate resistor

$$I_{RRM} = f(R_{gon})$$


**At**

$$T_j = 25/125 \text{ } ^{\circ}\text{C}$$

$$V_R = 600 \text{ V}$$

$$I_F = 8 \text{ A}$$

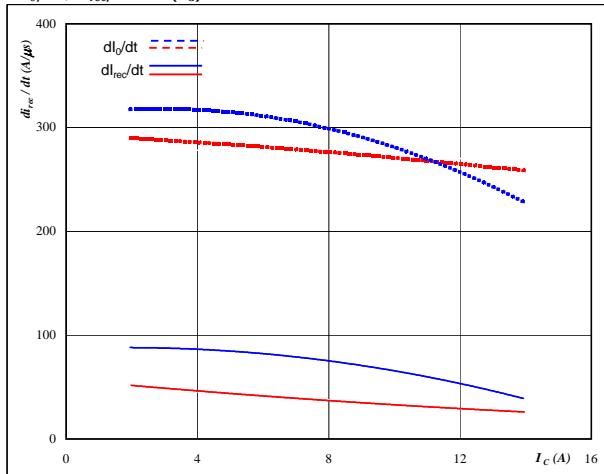
$$V_{GE} = \pm 15 \text{ V}$$

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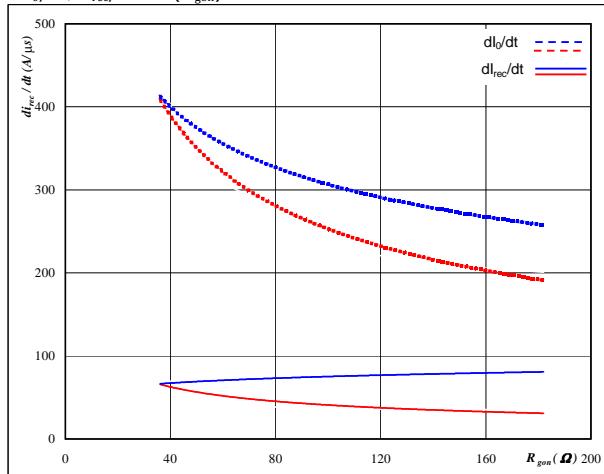
## Inverter Switch / Brake Switch / Inverter Diode / Brake Diode

**figure 17.**

**Typical rate of fall of forward and reverse recovery current as a function of collector current**  
 $dI_0/dt, dI_{rec}/dt = f(I_C)$


**FWD**
**figure 18.**

**Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor**  
 $dI_0/dt, dI_{rec}/dt = f(R_{gon})$


**FWD**
**At**

$T_j = 25/125 \text{ }^\circ\text{C}$   
 $V_{CE} = 600 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $R_{gon} = 81 \text{ } \Omega$

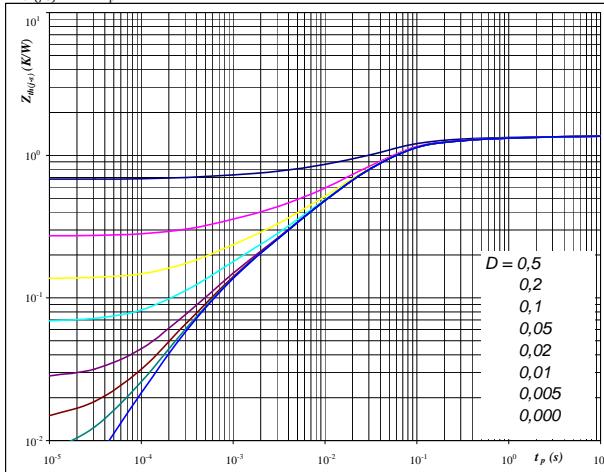
**At**

$T_j = 25/125 \text{ }^\circ\text{C}$   
 $V_R = 600 \text{ V}$   
 $I_F = 8 \text{ A}$   
 $V_{GE} = \pm 15 \text{ V}$

**figure 19.**

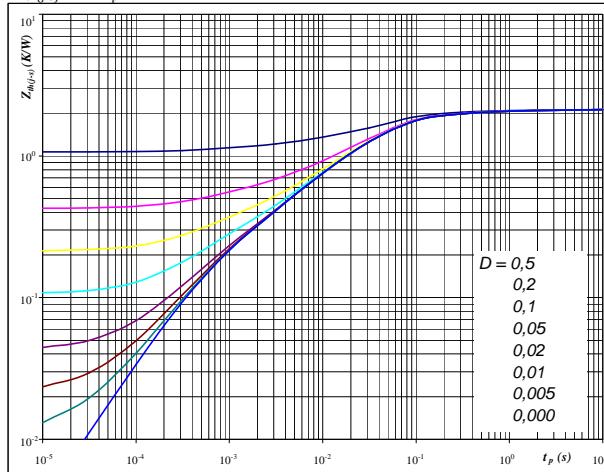
**IGBT transient thermal impedance as a function of pulse width**

$$Z_{th(j-s)} = f(t_p)$$


**IGBT**
**figure 20.**

**FWD transient thermal impedance as a function of pulse width**

$$Z_{th(j-s)} = f(t_p)$$


**FWD**
**At**

$D = t_p / T$   
 $R_{th(j-s)} = 1,36 \text{ K/W}$

**At**

$D = t_p / T$   
 $R_{th(j-s)} = 2,13 \text{ K/W}$

IGBT thermal model values

FWD thermal model values

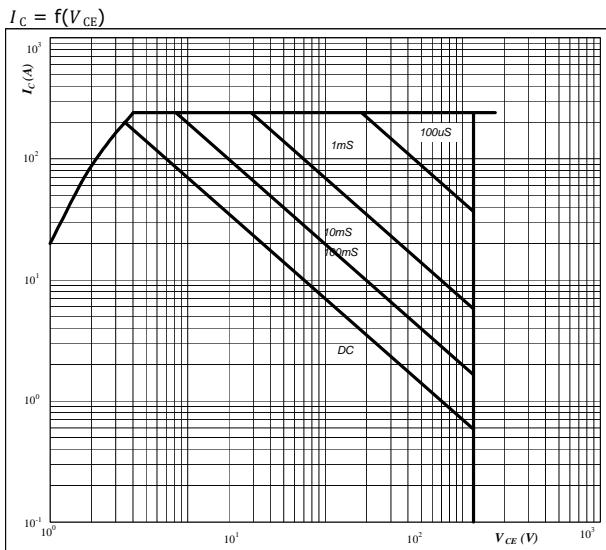
| $R$ (K/W) | Tau (s)  |
|-----------|----------|
| 4,79E-02  | 2,17E+00 |
| 1,18E-01  | 2,86E-01 |
| 6,64E-01  | 3,96E-02 |
| 2,94E-01  | 1,35E-02 |
| 1,54E-01  | 2,89E-03 |
| 8,15E-02  | 4,12E-04 |

| $R$ (K/W) | Tau (s)  |
|-----------|----------|
| 7,51E-02  | 3,40E+00 |
| 1,85E-01  | 4,48E-01 |
| 1,04E+00  | 6,21E-02 |
| 4,60E-01  | 2,12E-02 |
| 2,42E-01  | 4,52E-03 |
| 1,28E-01  | 6,46E-04 |

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## Inverter Switch / Brake Switch / Inverter Diode / Brake Diode

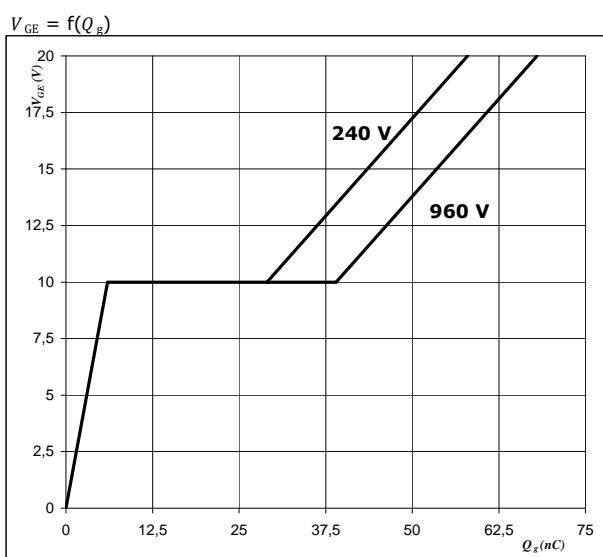
**figure 25.**  
**Safe operating area as a function  
 of collector-emitter voltage**


**At**

$D$  = single pulse  
 $T_s$  = 80 °C  
 $V_{GE}$  = ±15 V  
 $T_j$  =  $T_{jmax}$

**IGBT**

**figure 26.**  
**Gate voltage vs Gate charge**

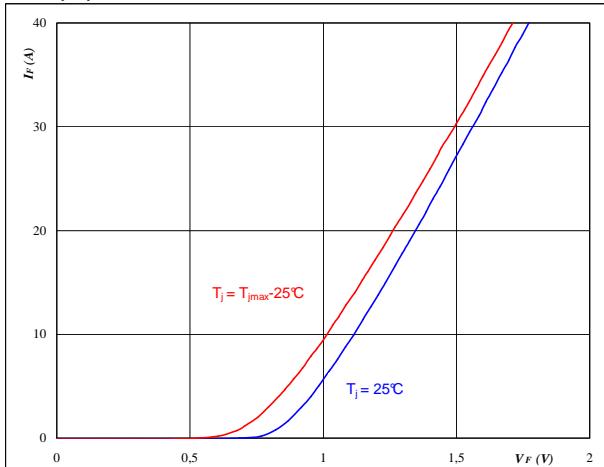

**At**

$I_C$  = 8 A

## Rectifier Diode

**figure 1.**
**Rectifier Diode**
**Typical diode forward current as  
a function of forward voltage**

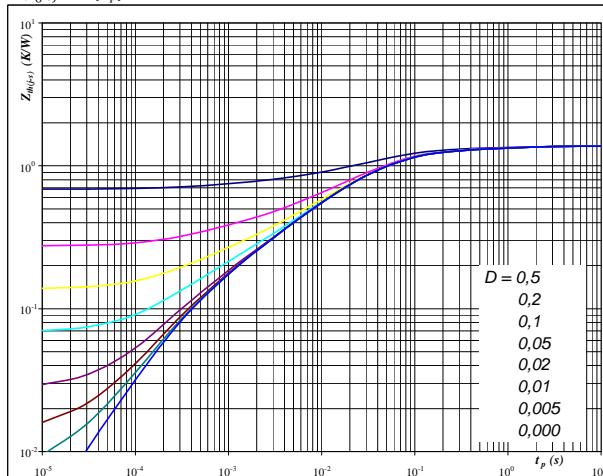
$$I_F = f(V_F)$$


**At**

$$t_p = 250 \mu\text{s}$$

**figure 2.**
**Rectifier Diode**
**Diode transient thermal impedance  
as a function of pulse width**

$$Z_{th(j-s)} = f(t_p)$$


**At**

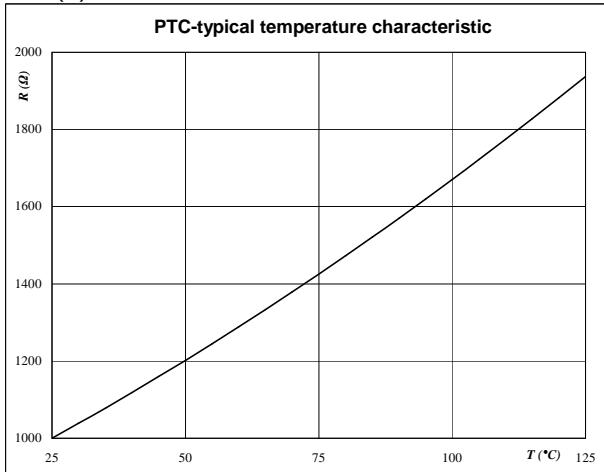
$$D = t_p / T$$

$$R_{th(j-s)} = 1,37 \text{ K/W}$$

## Thermistor

**figure 1.**
**Thermistor**
**Typical PTC characteristic  
as a function of temperature**

$$R = f(T)$$



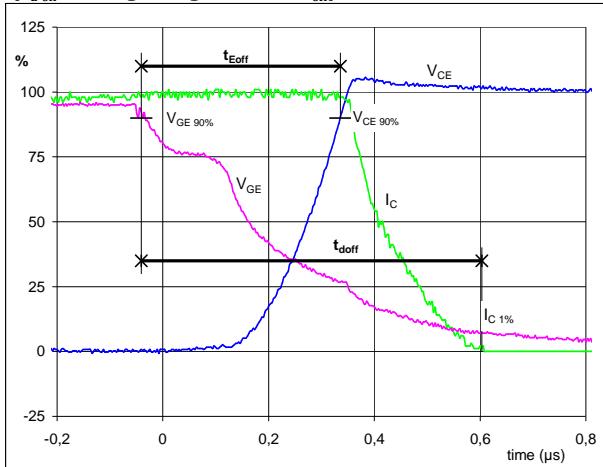
## Switching Definitions Output Inverter

**General conditions**

|            |          |
|------------|----------|
| $T_j$      | = 125 °C |
| $R_{gon}$  | = 81 Ω   |
| $R_{goff}$ | = 81 Ω   |

**figure 1.**

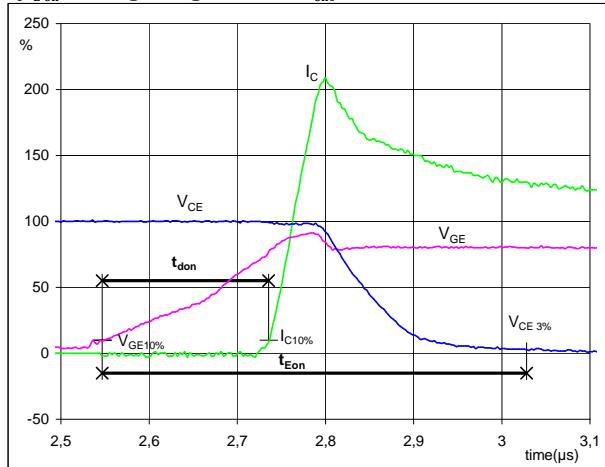
**IGBT**  
**Turn-off Switching Waveforms & definition of  $t_{doff}$ ,  $t_{Eoff}$**   
 $(t_{Eoff} = \text{integrating time for } E_{off})$



$V_{GE}(0\%) = -15$  V  
 $V_{GE}(100\%) = 15$  V  
 $V_C(100\%) = 600$  V  
 $I_C(100\%) = 8$  A  
 $t_{doff} = 0,39$  μs  
 $t_{Eoff} = 0,64$  μs

**figure 2.**

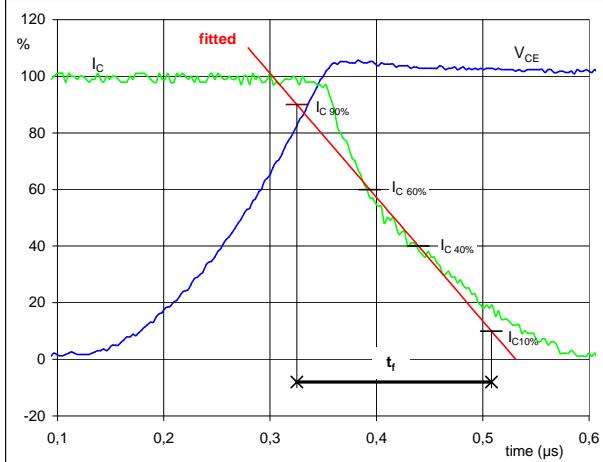
**IGBT**  
**Turn-on Switching Waveforms & definition of  $t_{don}$ ,  $t_{Eon}$**   
 $(t_{Eon} = \text{integrating time for } E_{on})$



$V_{GE}(0\%) = -15$  V  
 $V_{GE}(100\%) = 15$  V  
 $V_C(100\%) = 600$  V  
 $I_C(100\%) = 8$  A  
 $t_{don} = 0,04$  μs  
 $t_{Eon} = 0,48$  μs

**figure 3.**

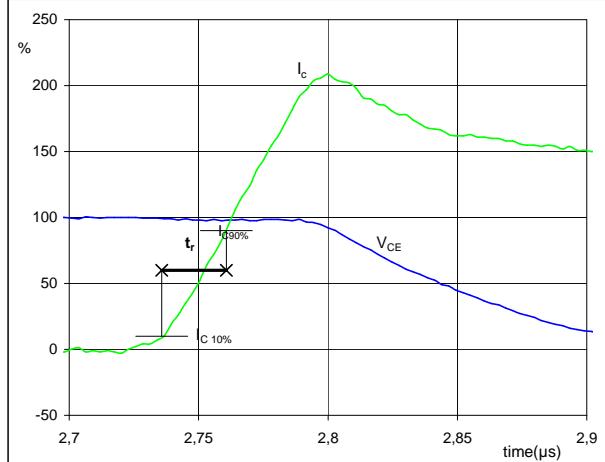
**IGBT**  
**Turn-off Switching Waveforms & definition of  $t_f$**



$V_C(100\%) = 600$  V  
 $I_C(100\%) = 8$  A  
 $t_f = 0,17$  μs

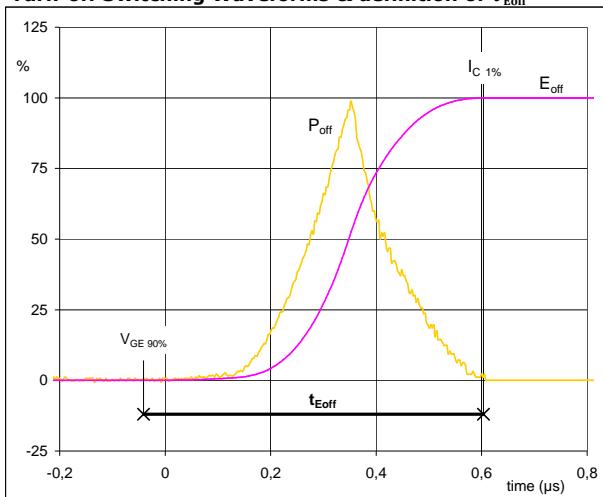
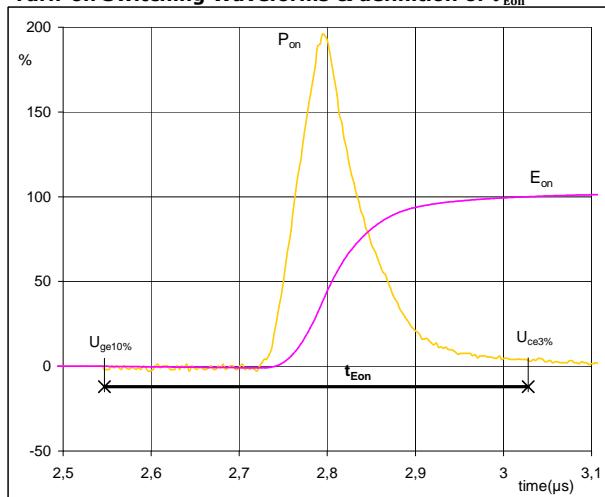
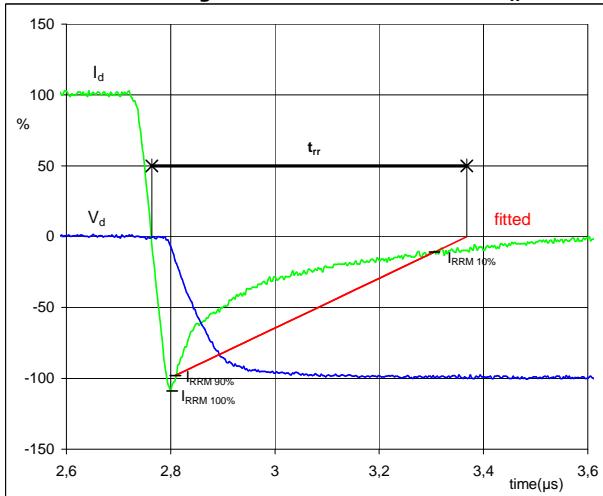
**figure 4.**

**IGBT**  
**Turn-on Switching Waveforms & definition of  $t_r$**



$V_C(100\%) = 600$  V  
 $I_C(100\%) = 8$  A  
 $t_r = 0,03$  μs

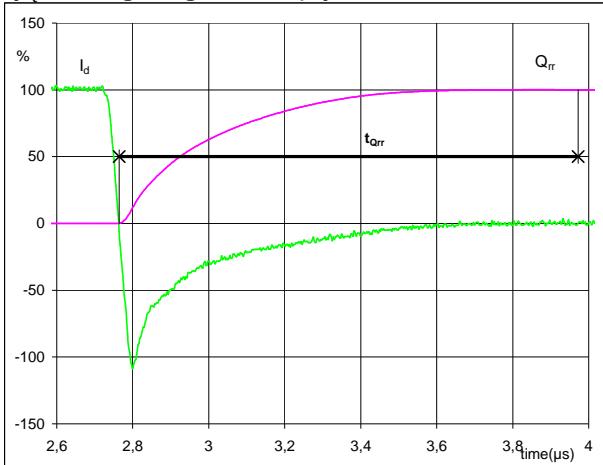
## Switching Definitions Output Inverter

**figure 5.****IGBT****Turn-off Switching Waveforms & definition of  $t_{Eoff}$** **figure 6.****IGBT****Turn-on Switching Waveforms & definition of  $t_{Eon}$** **figure 7.****IGBT****Turn-off Switching Waveforms & definition of  $t_{rr}$** 

## Switching Definitions Output Inverter

**figure 8.****FWD**

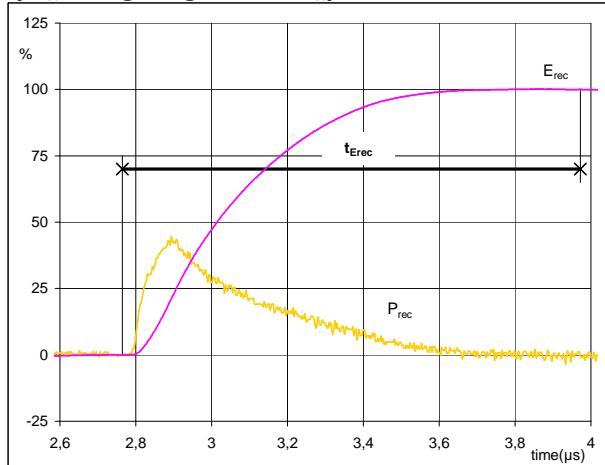
**Turn-on Switching Waveforms & definition of  $t_{Qrr}$**   
 $(t_{Qrr} = \text{integrating time for } Q_{rr})$



$I_d$  (100%) = 8 A  
 $Q_{rr}$  (100%) = 1,77  $\mu\text{C}$   
 $t_{Qrr}$  = 1,21  $\mu\text{s}$

**figure 9.****FWD**

**Turn-on Switching Waveforms & definition of  $t_{Erec}$**   
 $(t_{Erec} = \text{integrating time for } E_{rec})$



$P_{rec}$  (100%) = 4,79 kW  
 $E_{rec}$  (100%) = 0,75 mJ  
 $t_{Erec}$  = 1,21  $\mu\text{s}$



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V23990-K209-A-PM

datasheet

| Ordering Code & Marking  |                       |  |  |
|--|-----------------------|--|--|
| Version  | Ordering Code         |  |  |
| With std lid (6.5mm height) + no thermal grease                                  | V23990-K209-A-/0A/-PM |  |  |
| With thin lid (2.8mm height) + no thermal grease                                 | V23990-K209-A-/0B/-PM |  |  |
| With std lid (6.5mm height) + thermal grease (0,8 W/mK, P12, silicone-based)     | V23990-K209-A-/1A/-PM |  |  |
| With thin lid (2.8mm height) + thermal grease (0,8 W/mK, P12, silicone-based)    | V23990-K209-A-/1B/-PM |  |  |
| With std lid (6.5mm height) + thermal grease (2,5 W/mK, TG20032, silicone-free)  | V23990-K209-A-/4A/-PM |  |  |
| With thin lid (2.8mm height) + thermal grease (2,5 W/mK, TG20032, silicone-free) | V23990-K209-A-/4B/-PM |  |  |
| With std lid (6.5mm height) + thermal grease (2,5 W/mK, HPTP, silicone-based)    | V23990-K209-A-/5A/-PM |  |  |
| With thin lid (2.8mm height) + thermal grease (2,5 W/mK, HPTP, silicone-based)   | V23990-K209-A-/5B/-PM |  |  |

VIN WWYY  
NNNNNNVV UL  
LLLLL SSSS

| Text       | VIN        | Date code | Name&Ver  | UL    | Lot  | Serial |
|------------|------------|-----------|-----------|-------|------|--------|
| Type&Ver   | WWYY       | NNNNNNVV  | UL        | LLLLL | SSSS |        |
| Datamatrix | Lot number | Serial    | Date code |       |      |        |
|            | NNNNNNVV   | LLLLL     | SSSS      | WWYY  |      |        |

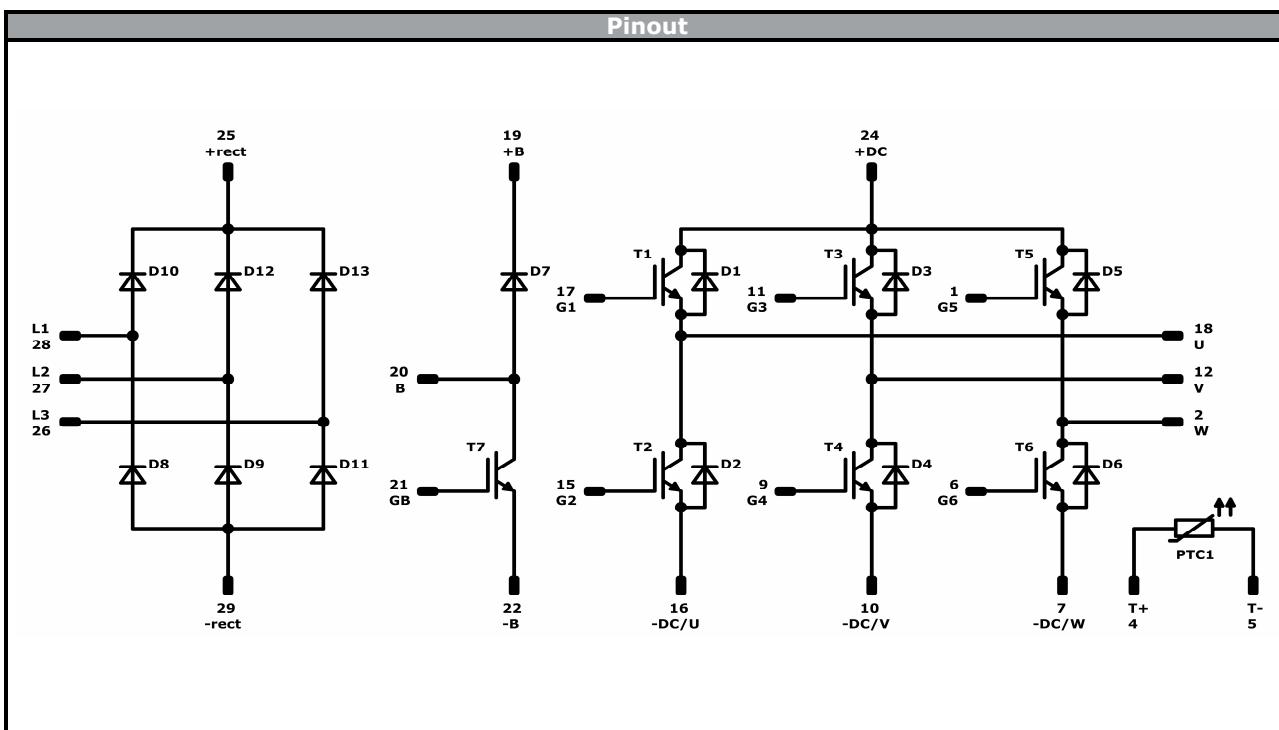
  

### Outline

| Pad table [mm] |               |       |          |
|----------------|---------------|-------|----------|
| Pad            | X             | Y     | Function |
| 1              | 15,93         | -14,6 | G5       |
| 2              | 15,93         | -9,8  | W        |
| 3              | Not assembled |       |          |
| 4              | 15,93         | -0,2  | +T       |
| 5              | 15,93         | 7,62  | -T       |
| 6              | 15,93         | 12,62 | G6       |
| 7              | 15,93         | 15,8  | -DC/W    |
| 8              | Not assembled |       |          |
| 9              | 8,23          | 12,62 | G4       |
| 10             | 8,23          | 15,8  | -DC/V    |
| 11             | 7,73          | -14,6 | G3       |
| 12             | 7,73          | -9,8  | V        |
| 13             | Not assembled |       |          |
| 14             | Not assembled |       |          |
| 15             | 0,53          | 12,62 | G2       |
| 16             | 0,53          | 15,8  | -DC/U    |
| 17             | -0,47         | -14,6 | G1       |
| 18             | -0,47         | -9,8  | U        |
| 19             | -5,47         | -5    | +B       |
| 20             | -5,47         | 5,35  | B        |
| 21             | -7,17         | 12,62 | GB       |
| 22             | -7,17         | 15,8  | -B       |
| 23             | Not assembled |       |          |
| 24             | -8,07         | -9,8  | +DC      |
| 25             | -15,02        | -15,8 | +RECT    |
| 26             | -15,02        | -9,8  | L3       |
| 27             | -15,02        | 0     | L2       |
| 28             | -15,02        | 9,8   | L1       |
| 29             | -15,02        | 15,8  | -RECT    |

X
Y

Pad positions refers to center point. For more informations on pad design please see package data.

**Identification**

| ID     | Component | Voltage | Current | Function        | Comment |
|--------|-----------|---------|---------|-----------------|---------|
| D8-D13 | Rectifier | 1600 V  | 25 A    | Rectifier Diode |         |
| T1-T6  | IGBT      | 1200 V  | 8 A     | Inverter Switch |         |
| D1-D6  | FWD       | 1200 V  | 12 A    | Inverter Diode  |         |
| T7     | IGBT      | 1200 V  | 8 A     | Brake Switch    |         |
| D7     | FWD       | 1200 V  | 12 A    | Brake Diode     |         |
| PTC1   | PTC       |         |         | Thermistor      |         |



Vincotech

**V23990-K209-A-PM**

datasheet

| <b>Packaging instruction</b>      |            | >SPQ | Standard | <SPQ | Sample |
|-----------------------------------|------------|------|----------|------|--------|
| Standard packaging quantity (SPQ) | <b>120</b> |      |          |      |        |

| <b>Handling instruction</b>   |
|---|
| Handling instructions for MiniSkiP® 1 packages see vincotech.com website. |

| <b>Package data</b>  |
|--|
| Package data for MiniSkiP® 1 packages see vincotech.com website. |

| <b>UL recognition and file number</b>   |
|---|
| This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website. |



| <b>Document No.:</b> | <b>Date:</b> | <b>Modification:</b>             | <b>Pages</b>  |
|----------------------|--------------|----------------------------------|---------------|
| V23990-K209-A-D6-14  | 27 Sep. 2018 | Thermal interface change to HPTP | 1,2,3,8,10,14 |

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.